2SD1707

Silicon NPN epitaxial planar type

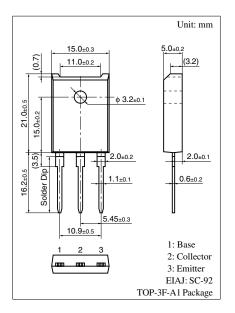
For power switching Complementary to 2SB1156

■ Features

- ullet Low collector to emitter saturation voltage $V_{CE(sat)}$
- ullet Satisfactory linearity of forward current transfer ratio h_{FE}
- Large collector current I_C
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit
Collector to base voltage		V_{CBO}	130	V
Collector to emitter voltage		V_{CEO}	80	V
Emitter to base voltage		V_{EBO}	7	V
Peak collector current		I_{CP}	30	A
Collector current		I_C	20	A
Collector power	$T_C = 25^{\circ}C$	P_{C}	100	W
dissipation	$T_a = 25^{\circ}C$		3	
Junction temperature		T _j	150	°C
Storage temperature		T_{stg}	-55 to +150	°C



■ Electrical Characteristics $T_C = 25$ °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 100 \text{ V}, I_{E} = 0$			10	μΑ
Emitter cutoff current	I_{EBO}	$V_{EB} = 5 \text{ V}, I_{C} = 0$			50	μΑ
Collector to emitter voltage	V_{CEO}	$I_C = 10 \text{ mA}, I_B = 0$	80			V
Forward current transfer ratio	h _{FE1}	$V_{CE} = 2 \text{ V}, I_{C} = 0.1 \text{ A}$	45			
	h _{FE2} *	$V_{CE} = 2 \text{ V}, I_{C} = 3 \text{ A}$	90		260	
	h _{FE3}	$V_{CE} = 2 \text{ V}, I_{C} = 10 \text{ A}$	30			
Collector to emitter saturation voltage	V _{CE(sat)1}	$I_C = 8 \text{ A}, I_B = 0.4 \text{ A}$			0.5	V
	V _{CE(sat)2}	$I_C = 20 \text{ A}, I_B = 2 \text{ A}$			1.5	V
Base to emitter saturation voltage	V _{BE(sat)1}	$I_C = 8 \text{ A}, I_B = 0.4 \text{ A}$			1.5	V
	V _{BE(sat)2}	$I_C = 20 \text{ A}, I_B = 2 \text{ A}$			2.5	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.5 \text{ A}, f = 1 \text{ MHz}$		20		MHz
Turn-on time	t _{on}	$I_C = 8 \text{ A}, I_{B1} = 0.8 \text{ A}, I_{B2} = -0.8 \text{ A},$		0.5		μs
Storage time	t _{stg}	$V_{CC} = 50 \text{ V}$		2.0		μs
Fall time	t _f			0.2		μs

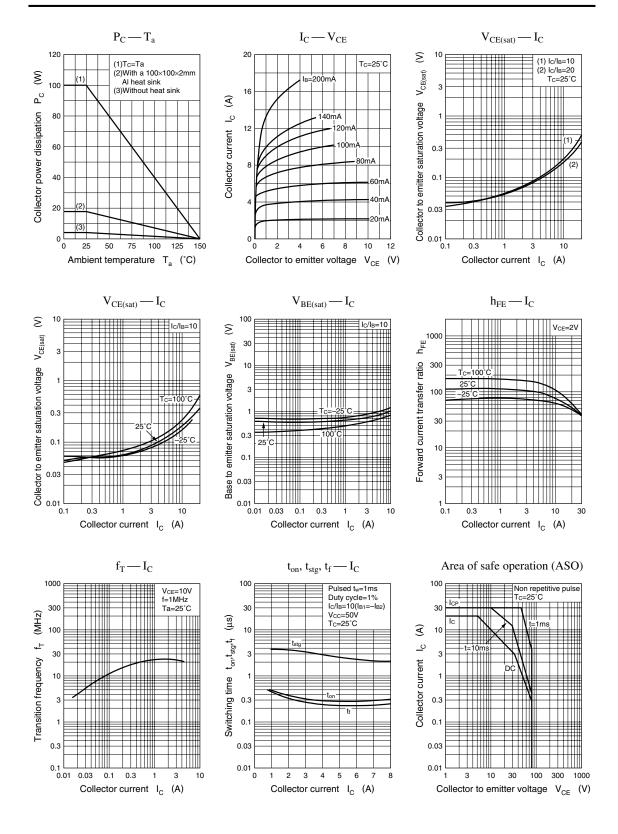
Note) *: Rank classification

Rank	Q	Р			
h _{FE2}	90 to 180	130 to 260			

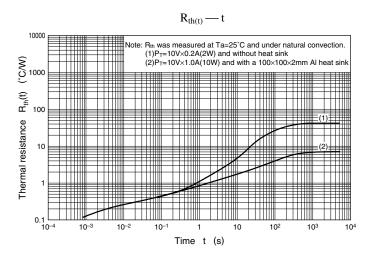
Ordering can be made by the common rank (PQ rank h_{FE2} = 90 to 260) in the rank classification.

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Power Transistors 2SD1707



Panasonic 321



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